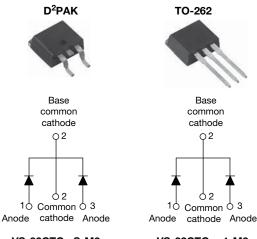
Www.vishay.com

Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 15 A



VS-32CTQ...S-M3

VS-32CTQ ... -1-M3

PRODUCT SUMMARY					
I <sub>F(AV)</sub>	2 x 15 A				
V <sub>R</sub>	25 V, 30 V				
V <sub>F</sub> at I <sub>F</sub>	0.40 V				
I <sub>RM</sub> max.	97 mA at 125°C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA				
Diode variation	Common cathode				

### FEATURES

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	30	А				
V <sub>RRM</sub>		25, 30	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	900	А				
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.40	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-32CTQ025S-M3 VS-32CTQ025-1-M3	VS-32CTQ030S-M3 VS-32CTQ030-1-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	25	30	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	25	50	v

Revision: 15-Aug-15 1 Document Number: 94936 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_{C}$ = 115 °C	C, rectangular waveform	30			
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	А		
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	250			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11	.10 mH	13	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim	3	А			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		15 A	T <sub>.1</sub> = 25 °C	0.49		
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.58	V	
	VFM ()	15 A	T <sub>J</sub> = 125 °C	0.40		
		30 A	1j = 125 0	0.53		
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1.75	mA	
See fig. 2		T <sub>J</sub> = 125 °C	VR - Haleu VR	97		
Threshold voltage	V <sub>F(TO)</sub>			0.233	V	
Forward slope resistance	r <sub>t</sub>	$r_t$ $T_J = T_J$ maximum		9.09	mΩ	
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	1300	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANI	CAL SPE	CIFICAT	IONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C		
Maximum thermal resistance, junction to case per leg Typical thermal resistance, case to heatsink		R <sub>thJC</sub>	DC operation See fig. 4	3.25	°C/W		
		R <sub>thCS</sub>	R <sub>thCS</sub> Mounting surface, smooth and greased		C/ VV		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf ⋅ cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
			$\rho_{\rm resc} = t_{\rm resc} = T \rho_{\rm resc} \rho_{\rm resc} = \rho_{\rm resc} \rho_{\rm resc} \rho_{\rm resc} = r_{\rm resc} \rho_{\rm resc} \rho_{\rm resc}$	32CT0	Q025S		
Marking device			Case style TO-263AB (D <sup>2</sup> PAK)	32CT0	2030S		
			Case style TO 26244	32CTQ025-1			
			Case style TO-262AA	32CTC	32CTQ030-1		

Revision: 15-Aug-15 Document Number: 94936 2 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



## VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

### **Vishay Semiconductors**

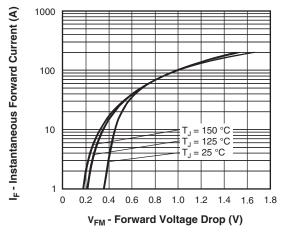
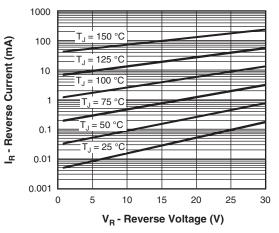
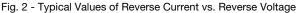
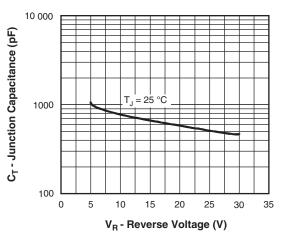


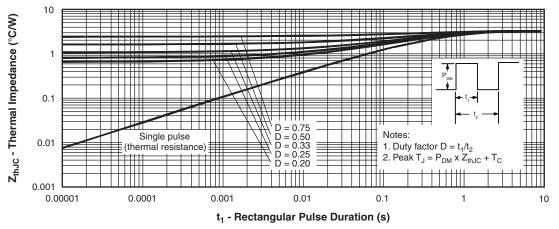
Fig. 1 - Maximum Forward Voltage Drop Characteristics



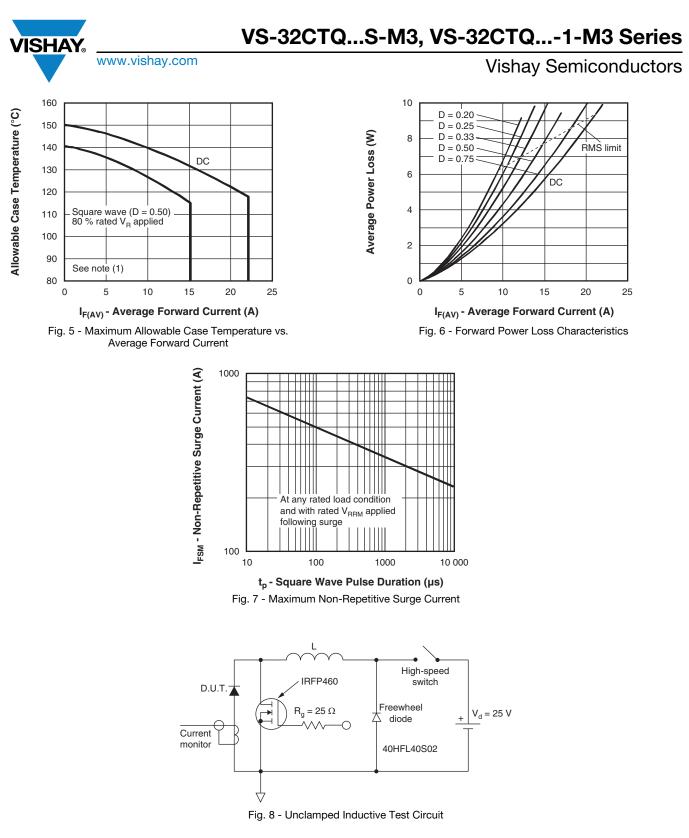












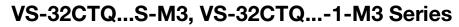
#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$

Revision: 15-Aug-15

4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

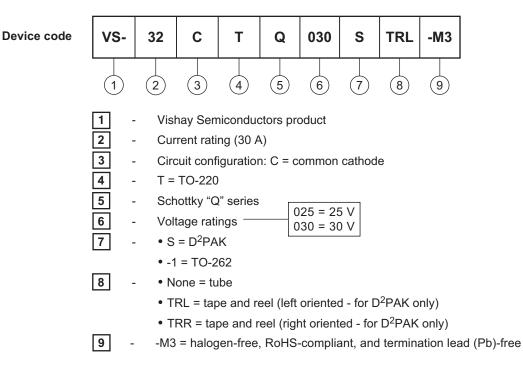


### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**

www.vishay.com

/ISHA



ORDERING INFORMATION						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-32CTQ025S-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ025STRR-M3	800	800	13" diameter reel			
VS-32CTQ025STRL-M3	800	800	13" diameter reel			
VS-32CTQ025-1-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ030S-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ030STRR-M3	800	800	13" diameter reel			
VS-32CTQ030STRL-M3	800	800	13" diameter reel			
VS-32CTQ030-1-M3	50	1000	Antistatic plastic tubes			

	LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046					
Dimensions	TO-262AA	www.vishay.com/doc?95419					
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?95032					

5

## **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

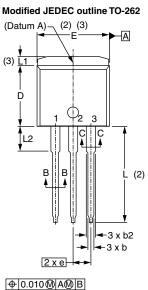


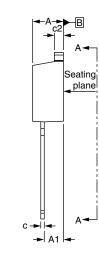
## **Outline Dimensions**

**Vishay Semiconductors** 

**TO-262** 

#### **DIMENSIONS** in millimeters and inches

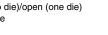


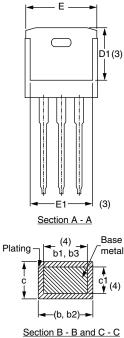


Lead assignments



**Diodes** 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

SYMBOL	MILLIM	ETERS	INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	c1 0.38 0.58	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.10	0 BSC	
L	13.46 14.10		0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56 3.71		0.140	0.146	

#### Notes

Revision: 04-Oct-10

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Document Number: 95419 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.